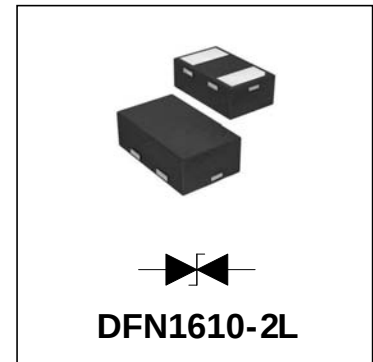


Features

- 2280Watts peak pulse power ($t_p = 8/20\mu s$)
- Bidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Protection one data/power line to:
- IEC 61000-4-2 $\pm 30kV$ contact $\pm 30kV$ air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 120A (8/20 μs)



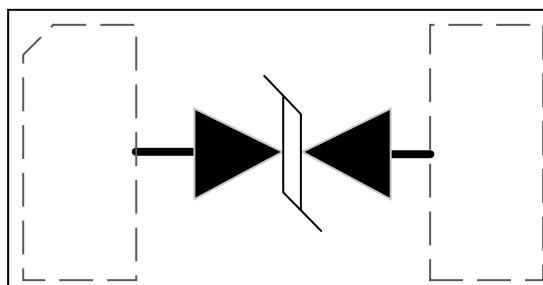
Applications

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

Mechanical Data

- DFN1610 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Schematic & PIN Configuration

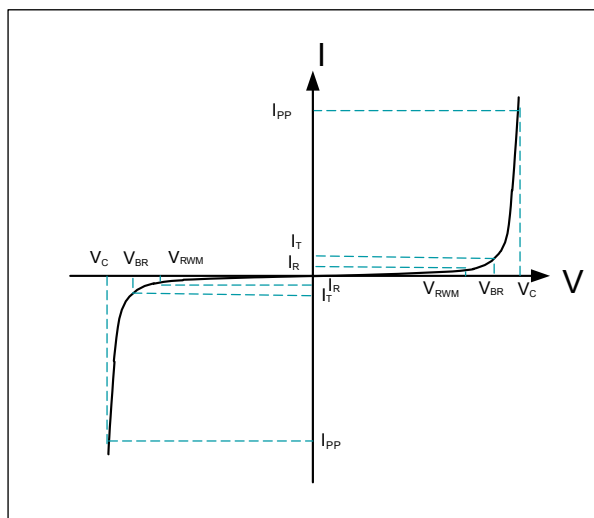


Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$)	P_{PP}	2280	Watts
Peak Pulse Current ($t_p = 8/20\mu s$)(note1)	I_{PP}	120	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V_{ESD}	30 30	kV
Lead Soldering Temperature	T_L	260(10seconds)	$^{\circ}C$
Junction Temperature	T_J	-55 to + 125	$^{\circ}C$
Storage Temperature	T_{stg}	-55 to + 125	$^{\circ}C$

Electrical Parameters (TA = 25°C unless otherwise noted)

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current

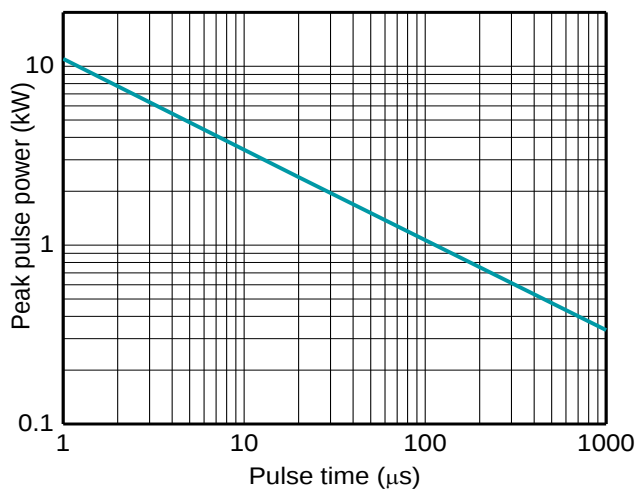


Note: 8/20μs pulse waveform.

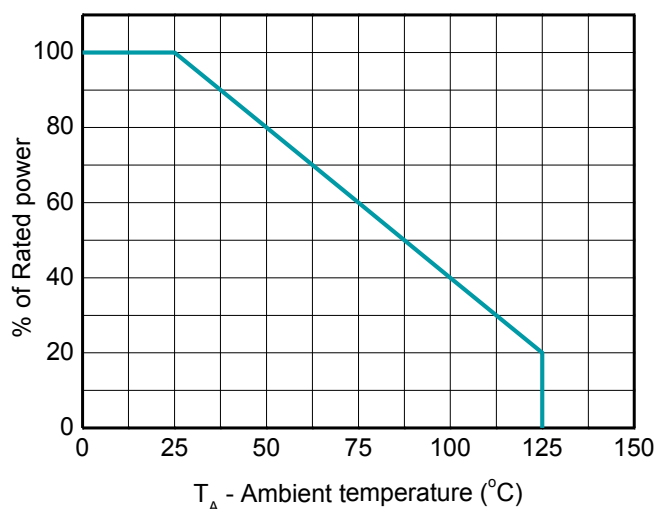
Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				5	V
Reverse Breakdown Voltage	V_{BR}	$I_T = 1mA$	5.6		8	V
Reverse Leakage Current	I_R	$V_{RWM} = 4.5V, T = 25^{\circ}C$		0.1	0.5	μA
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$		120		A
Clamping Voltage	V_C	$I_{PP} = 120A, t_p = 8/20\mu s$		19		V
Junction Capacitance	C_j	$V_R = 0V, f = 1MHz$		550		pF

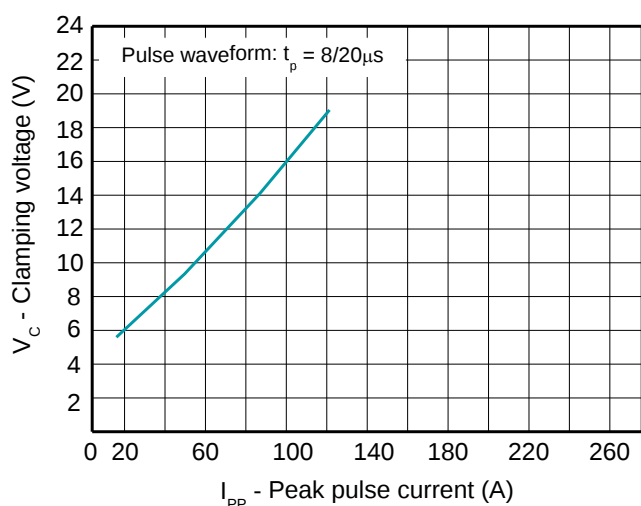
Typical Characteristics



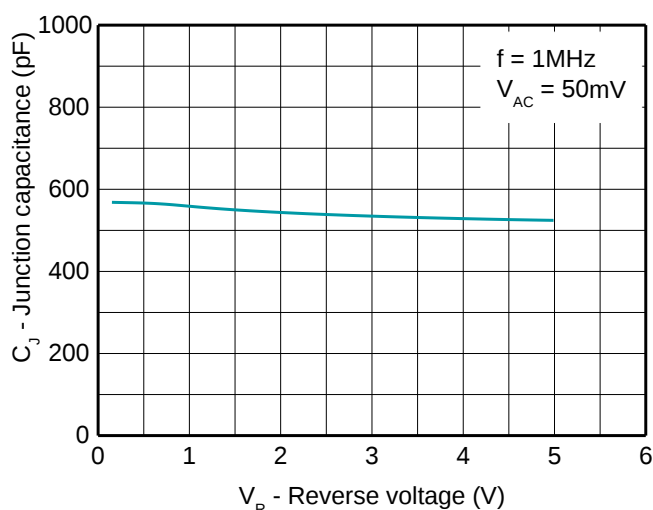
Non-repetitive peak pulse power vs. Pulse time



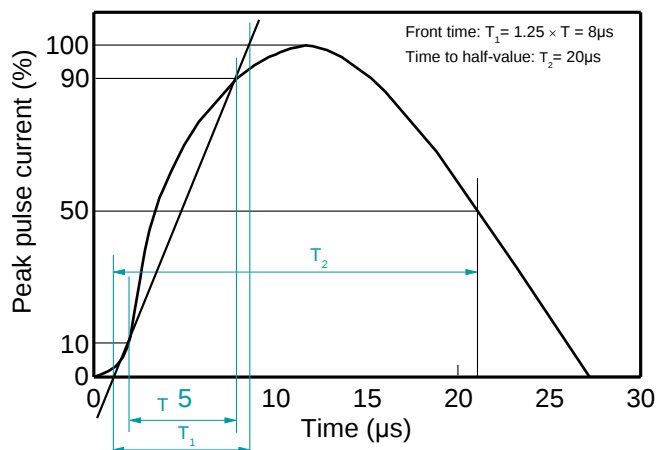
Power derating vs. Ambient temperature



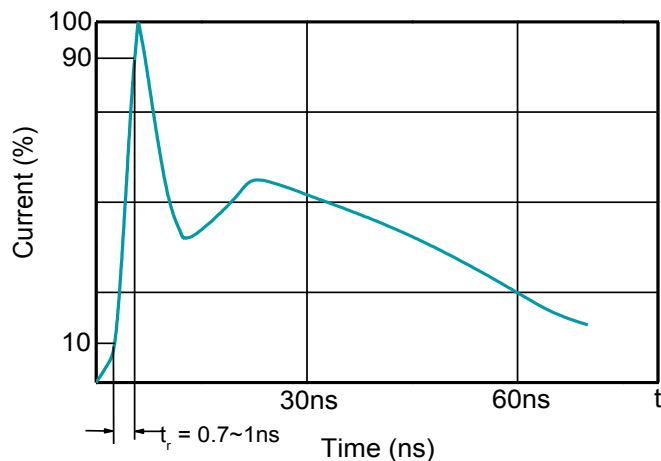
Clamping voltage vs. Peak pulse current



Capacitance vs. Reverse voltage

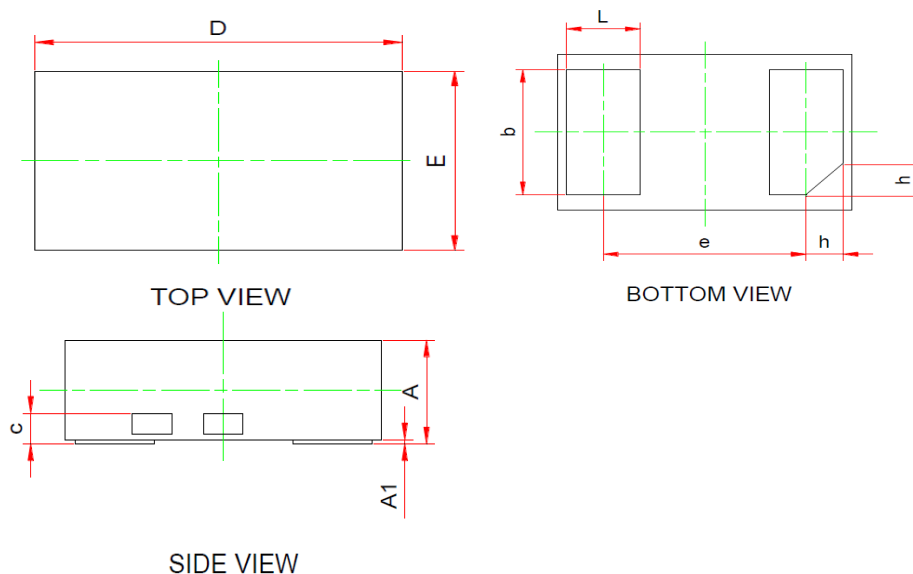


8/20μs waveform per IEC61000-4-5



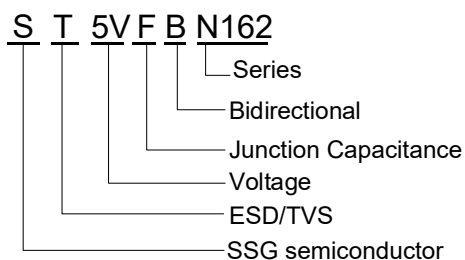
Contact discharge current waveform per IEC61000-4-2

Outline Drawing – DFN1610



Symbol	Dimensions In Millimeters		
	Min	Nom	Max
A	0.50	0.55	0.60
D	1.55	1.60	1.65
E	0.95	1.00	1.05
b	0.75	0.80	0.85
e	1.10		
h	0.20		
L	0.35	0.40	0.45
c	0.12		
A1	0.00	/	0.025

Part Numbering System



Device	Package	Shipping	MarKing	Parameter
ST5VFBN162	DFN1610-2L	3000/Tape&Reel	5H*	5H = Product Code T = Device Code